

40V +175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _C = +25°C	
40V	0.9 m Ω @ V _{GS} = 10V	278A	

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Engine management systems
- Body control electronics
- DC-DC converters

Features and Benefits

- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching (UIS) Test in Production -Ensures More Reliable and Robust End Application
- Thermally Efficient Package-Cooler Running Applications
- High Conversion Efficiency
- Wettable Flank for Improved Optical Inspection
- Low R_{DS(ON)} Minimizes On-State Losses < 1.1mm Package Profile Ideal for Thin Applications Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMTH4M90SPSWQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

Mechanical Data

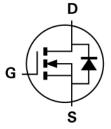
- Package: PowerDI®5060-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.097 grams (Approximate)



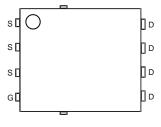
PowerDI5060-8/SWP (Type UX)

Top View

Bottom View



Internal Schematic



Top View Pin Configuration

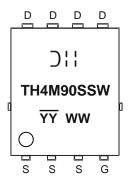
Ordering Information (Note 4)

Part Number	Package	Packing		
Fait Number	Package	Qty.	Carrier	
DMTH4M90SPSWQ-13	PowerDI5060-8/SWP (Type UX)	2500	Tape & Reel	

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



PowerDI5060-8/SWP (Type UX)

☐ I = Manufacturer's Marking TH4M90SSW = Product Type Marking Code YYWW or $\overline{YY}WW = Date Code Marking$ YY or \overline{YY} = Last Two Digits of Year (ex: 24 = 2024) WW = Week Code (01 to 53)



Maximum Ratings (@ $T_A = +25$ °C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	VDSS	40	V	
Gate-Source Voltage	V _{GSS}	±20	V	
Continuous Drain Current, V _{GS} = 10V (Note 6)	$T_C = +25^{\circ}C$ $T_C = +100^{\circ}C$	ID	278 196	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	Ірм	1112	Α	
Continuous Body Diode Forward Current (Note 6)	Tc = +25°C	Is	278	Α
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)	lsм	1112	Α	
Avalanche Current, L = 1mH	las	40	Α	
Avalanche Energy, L = 1mH	E _{AS}	800	mJ	

Thermal Characteristics

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)	$T_A = +25$ °C	P _D	2.6	W
Thermal Resistance, Junction to Ambient (Note 5)	RθJA	58	°C/W	
Total Power Dissipation (Note 6)	PD	125	W	
Thermal Resistance, Junction to Case (Note 6)	R _θ JC	1.2	°C/W	
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +175	°C	

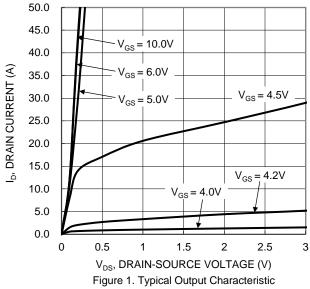
Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BVDSS	40		_	V	$V_{GS} = 0$, $I_D = 1mA$	
Zero Gate Voltage Drain Current	I _{DSS}		_	1	μA	$V_{DS} = 32V, V_{GS} = 0$	
Gate-Source Leakage	Igss		_	±100	nA	$V_{GS} = \pm 20V$, $V_{DS} = 0$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	Vgs(TH)	2	_	4	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$	
Static Drain-Source On-Resistance	RDS(ON)	_	0.7	0.9	mΩ	Vgs = 10V, ID = 20A	
Diode Forward Voltage	V_{SD}	_	0.8	1.3	V	$V_{GS} = 0$, $I_{S} = 20A$	
DYNAMIC CHARACTERISTICS (Note 8)	DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss	_	9434	_		V _{DS} = 20V, V _{GS} = 0, f = 1MHz	
Output Capacitance	Coss	_	4466	_	pF		
Reverse Transfer Capacitance	Crss		271	_			
Gate Resistance	Rg	_	2.3	_	Ω	$V_{DS} = 0$, $V_{GS} = 0$, $f = 1MHz$	
Total Gate Charge	Qg		115	_		V _{DD} = 20V, I _D = 20A, V _{GS} = 10V	
Gate-Source Charge	Qgs	_	29	_	nC		
Gate-Drain Charge	Q _{gd}	_	5	_			
Turn-On Delay Time	tD(ON)	_	16	_		$V_{DD} = 20V, V_{GS} = 10V,$ $I_{D} = 20A, R_{g} = 2.5\Omega$	
Turn-On Rise Time	t _R	_	37	_			
Turn-Off Delay Time	tD(OFF)	-	82	_	ns		
Turn-Off Fall Time	tF	_	41	_			
Reverse-Recovery Time	t _{RR}		129	_	ns	I- 204 di/dt 1004/110	
Reverse-Recovery Charge	Q _{RR}	_	391	_	nC	I _F = 20A, di/dt = 100A/μs	

Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
 Thermal resistance from junction to soldering point (on the exposed drain pad).
 Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to product testing.







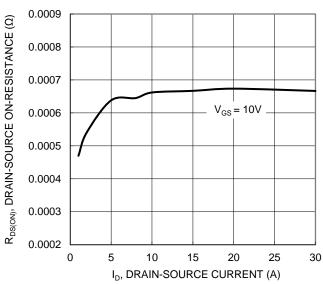


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

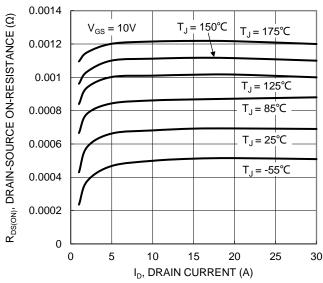
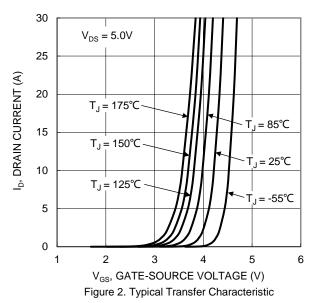
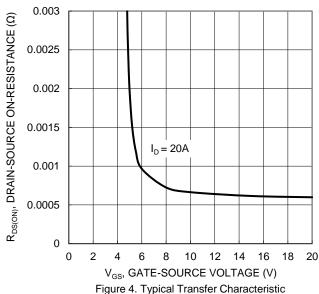


Figure 5. Typical On-Resistance vs. Drain Current and Junction Temperature





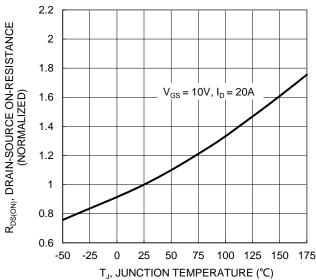


Figure 6. On-Resistance Variation with Junction Temperature





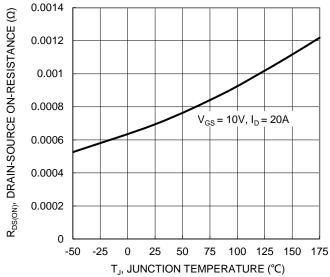


Figure 7. On-Resistance Variation with Junction Temperature

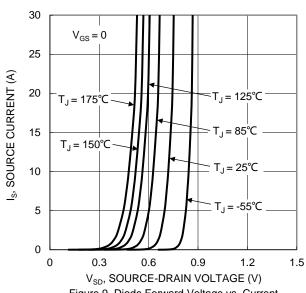


Figure 9. Diode Forward Voltage vs. Current

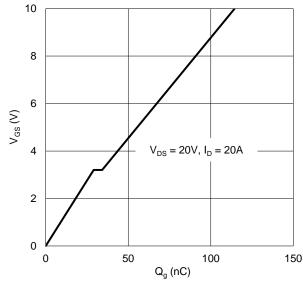


Figure 11. Gate Charge

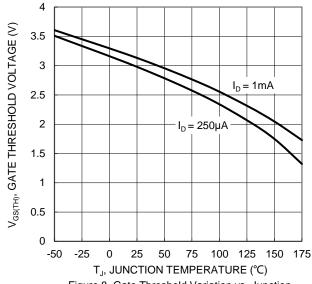
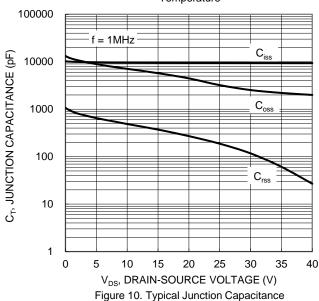


Figure 8. Gate Threshold Variation vs. Junction Temperature



10000 R_{DS(ON)} Limited 1000 DRAIN CURRENT (A) 100 10 = 10ms $T_{J(Max)} = 175^{\circ}C$ = 100ms $T_{\rm C} = 25^{\circ}{\rm C}$ Single Pulse DUT on Infinite DC 0.1 Heatsink $V_{GS} = 10V$ 0.01 0.1 10 100 V_{DS} , DRAIN-SOURCE VOLTAGE (V)

Figure 12. SOA, Safe Operation Area



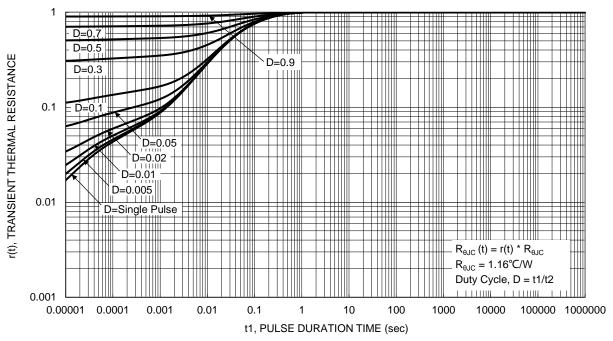


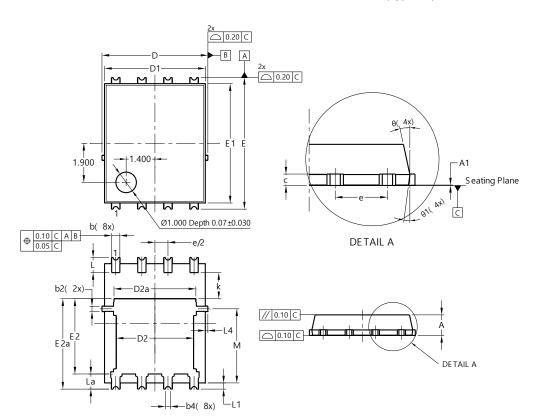
Figure 13. Transient Thermal Resistance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8/SWP (Type UX)

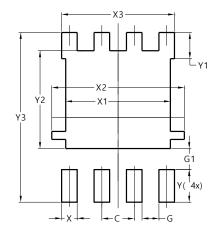


PowerDI5060-8/SWP (Type UX)					
Dim	Min Max		Тур		
Α	0.90	1.10	1.00		
A1	0	0.05			
b	0.30	0.50	0.41		
b2	0.20	0.35	0.25		
b4	().25REF	=		
С	0.230	0.330	0.277		
D	5	.15 BS0)		
D1	4.70	5.10	4.90		
D2	3.56	3.96	3.76		
D2a	3.78	4.18	3.98		
Е	6	.40 BS0)		
E1	5.60	6.00	5.80		
E2	3.46	3.86	3.66		
E2a	4.195	4.595	4.395		
е	1.27BSC				
k	1.05				
L	0.635	0.835	0.735		
La	0.635	0.835	0.735		
L1	0.200	0.400	0.300		
L4	0.025	0.225	0.125		
M	3.205	4.005	3.605		
θ	10°	12°	11°		
θ1	6°	8°	7°		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8/SWP (Type UX)



Dimensions	Value (in mm)		
С	1.270		
G	0.660		
G1	0.820		
Х	0.610		
X1	4.100		
X2	5.190		
Х3	4.420		
Y	1.270		
Y1	1.020		
Y2	3.810		
Y3	6.610		



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